

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Rep <mark>etitive Peak Reverse</mark> Voltage	V <sub>RRM</sub>	100	V
For <mark>ward C</mark> ontinuous Current at T <sub>amb</sub> = 25 °C	IF	100 <sup>1)</sup>	mA
Repetitive Peak Forward Current at t <sub>p</sub> < 1 s, @ < 0.5, T <sub>amb</sub> = 25 °C	I <sub>FRM</sub>	350 <sup>1)</sup>	mA
Surge Forward Current at t <sub>p</sub> = 10 ms, T <sub>amb</sub> = 25 °C	ISFM	750 <sup>1)</sup>	mA
Power Dissipation, T <sub>amb</sub> = 25 °C	P <sub>tot</sub>	400 <sup>1)</sup>	mW
Junction Temperature	Tj	125	°C
Am <mark>bient Op</mark> erating Temperature Range	T <sub>amb</sub>	-65 to +125	°C
Storage Temperature Range	T <sub>S</sub>	-65 to +150	°C





## BAT41

## **ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified

Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage tested with 100 $\mu$ A / 300 $\mu$ s Pulses	V <sub>(BR)R</sub>	100	110	-	V
Forward Voltage Pulse Test $t_p = 300 \ \mu s$ at $I_F = 1 \ mA$ at $I_F = 200 \ mA$	V <sub>F</sub> V <sub>F</sub>		0.40	0.45 1.0	V V
Leakage Current Pulse Test $t_p = 300 \ \mu s$ at V <sub>R</sub> = 50 V, at T <sub>j</sub> = 25 °C at V <sub>R</sub> = 50 V, at T <sub>j</sub> = 100 °C	I <sub>R</sub> I <sub>R</sub>			100 20	nA μA
Capacitance at V <sub>R</sub> = 1 V, f = 1 MHz	C <sub>tot</sub>	-	2	-	pF
Reverse Recovery Time from $I_F = 10 \text{ mA}$ , to $I_R = 10 \text{ mA}$ to $I_R = 1 \text{ mA}$ $R_L = 100 \text{ Ohm}$	t <sub>rr</sub>	-	5	-	ns
Thermal Resistance Junction to Ambient Air	R <sub>thJA</sub>	-	_	300 <sup>1)</sup>	K/W
<sup>1)</sup> Valid provided that leads at a distance of 4 m	nm from case are	e kept at am	bient tempera	ature.	

